Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	51084	ferroelectric (ferro adj electric)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:04
L2	331	PCMO	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:05
L3	6	"Pr0.7Ca0.3MnO3"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/03/30 10:06
L4	. 229	colossal with Magnetoresistive	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:07
L5	. 326	colossal with (resistance resistive)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:08
L6	17531	schottky same diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:08
L7	305306	(resistive resistance) same element	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:09
L8	765	1 same 7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:09
L9	2450140	(resistive resistance)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:10

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L10	3211	1 same 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:10
L11	2026	10 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:21
L12	26745	cross near point	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:11
L13	5056	crosspoint	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 10:11
L14	30630	12 13	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:11
L15	78	11 and 14	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:19
L16	43248	resistive with element	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/03/30 10:20
L17	446	2 3 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:21
L18	18	11 and 17	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR ⁻	ON	2006/03/30 10:25
L19	162	"6185122"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 10:26

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L20	609	17 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/03/30 10:26
L21	425	20 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:28
L22	15	21 and 6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON:	2006/03/30 10:29
L23	609	2345	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:29
L24	15	22 and 23	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:41
L25	83	PCMO same colossal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 10:44
L26	95	PCMO same CMR	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:01
L27	270	colossal with magnetic	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:03
L28	178	27 same CMR	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:03
L29	18453	perovskite	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON.	2006/03/30 11:04

L30	128	CMR same 29	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:20
L31	198	29 same colossal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 11:16
L32		30 and Schottky	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:32
L33	32039	Schottky	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON ·	2006/03/30 11:21
L34	22	31 and 33	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:21
L35	18453	perovskite	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 11:33
L36	1569	35 same 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/03/30 11:34
L37	485	36 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 11:34
L38	35	37 and 33	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 12:12
L39	113	colossal with resistance with perovskite	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 12:13

L40	10	39 and schottky	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/03/30 12:35
L41	13	perovskite near (resistor resistive)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 12:42
L42	162	"6185122"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 12:42
L43	63	42 and (resistant resistive)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 12:49
L44	0	42 and CMR	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 12:49
L45	3	42 and colossal	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON ·	2006/03/30 13:08
L46	61997	"3" adj D	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 13:23
L47	346	46 near memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 13:21
L48	56036	isolation with layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 13:21
L49	12972	isolation adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 13:21

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L50	3	47 and 49	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/03/30 13:21
L51	3949	46 same memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 13:24
L52	167	51 and 48	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 13:25
L53	118	T-RAM.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON ⁻	2006/03/30 13:26
L54	1	53 and 48	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 13:26
L55	1228	matrix.as.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2006/03/30 13:26
L56	25	48 and 55	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 14:14
L57	7	"6906939"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/03/30 14:23
L58	162	"6185122"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 14:32
L59	77098	amorphous with silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2006/03/30 14:33

· L60	1790	non-crystalline with silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 14:33
L61	32039	schottky	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 14:33
L62	16903	61 with diode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 14:34
L63	342	59 same 62	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR .	ON .	2006/03/30 14:35
L64	151	63 and memory	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 15:20
L65	1	perovskite adj resistor	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 15:20
L66	0	perovskite adj resistive adj material	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 15:31
L67	24	perovskite same resistive adj material	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2006/03/30 15:43
L68	2	"6780755"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 15:43
L69	. 5	"6870755"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 15:58

L70	3	"6906309"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 15:59
L71	7	"6906939"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/03/30 15:59